

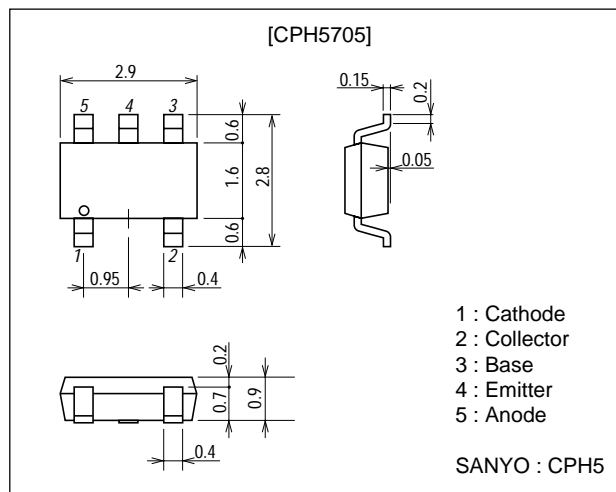
**CPH5705****DC / DC Converter Applications****Features**

- Composite type with a PNP transistor and a Schottky barrier diode contained in one package facilitating high-density mounting.
- The CPH5705 consists of two chips which are equivalent to the CPH3109 and the SBS004, respectively.
- Ultrasmall package facilitates miniaturization in end products.

Package Dimensions

unit : mm

2156

**Specifications****Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
[TR]				
Collector-to-Base Voltage	V _{CB0}		-30	V
Collector-to-Emitter Voltage	V _{CE0}		-30	V
Emitter-to-Base Voltage	V _{EB0}		-5	V
Collector Current	I _C		-3	A
Collector Current (Pulse)	I _{CP}		-5	A
Base Current	I _B		-600	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +125	°C
[SBD]				
Repetitive Peak Reverse Voltage	V _{RRM}		15	V
Non-repetitive Peak Reverse Surge Voltage	V _{RSM}		15	V
Average Output Current	I _O		1	A
Surge Forward Current	I _{FSM}	50Hz sine wave, 1cycle	10	A
Junction Temperature	T _J		-55 to +125	°C
Storage Temperature	T _{stg}		-55 to +125	°C

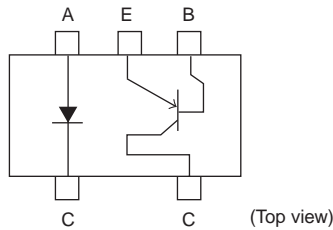
Marking : PE

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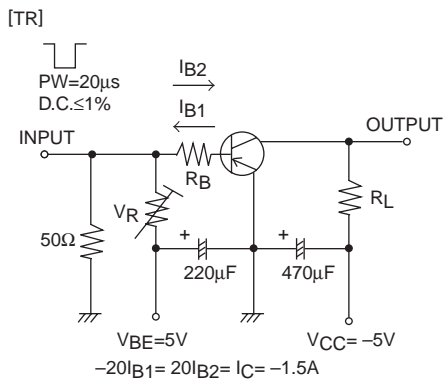
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[TR]						
Collector Cutoff Current	I_{CBO}	$V_{CB}=-12V, I_E=0$			-0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=-4V, I_C=0$			-0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=-2V, I_C=-0.5A$	200		560	
Gain Bandwidth Product	f_T	$V_{CE}=-2V, I_C=-0.5A$		380		MHz
Output Capacitance	C_{ob}	$V_{CB}=-10V, f=1MHz$		25		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-1.5A, I_B=-30mA$		-155	-230	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-1.5A, I_B=-30mA$		-0.83	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\mu A, I_E=0$	-30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, R_{BE}=\infty$	-30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-5			V
Turn-ON Time	t_{on}	See specified Test Circuit		50		ns
Storage Time	t_{stg}	See specified Test Circuit		270		ns
Fall Time	t_f	See specified Test Circuit		25		ns
[SBD]						
Reverse Voltage	V_R	$I_R=1mA$	15			V
Forward Voltage	V_{F1}	$I_F=0.5A$		0.30	0.35	V
	V_{F2}	$I_F=1A$		0.35	0.40	V
Reverse Current	I_R	$V_R=6V$			500	μA
Interterminal Capacitance	C	$V_R=10V, f=1MHz$		42		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100mA$, See specified Test Circuit			15	ns
Thermal Resistance	$R_{th j-a}$	Mounted on a ceramic board (600mm ² X0.8mm)		110		°C/W

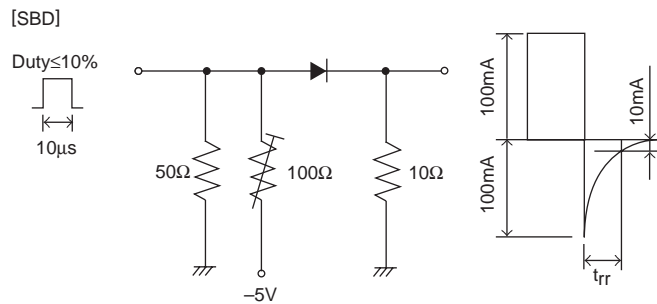
Electrical Connection

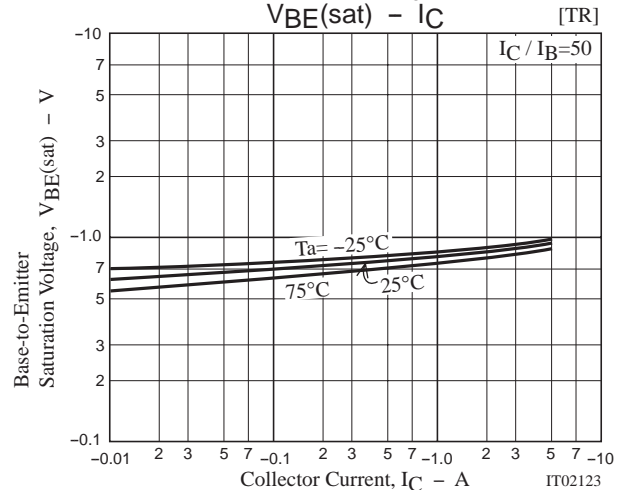
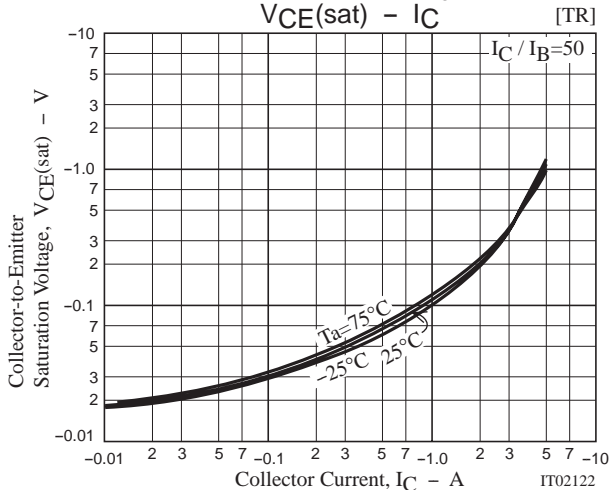
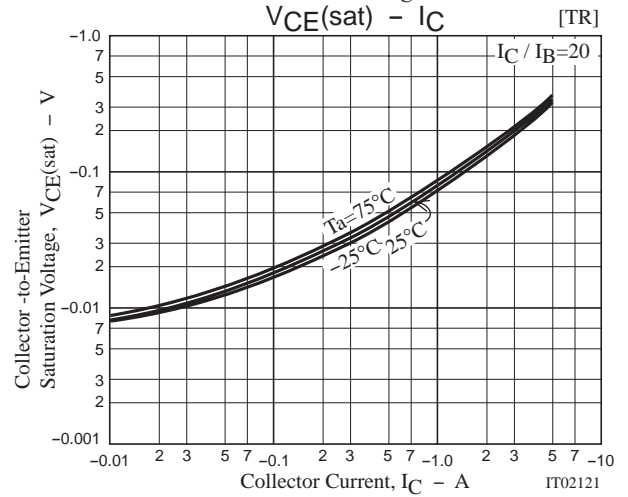
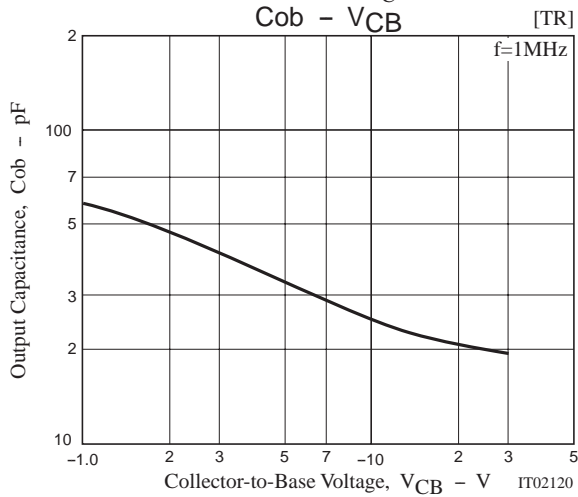
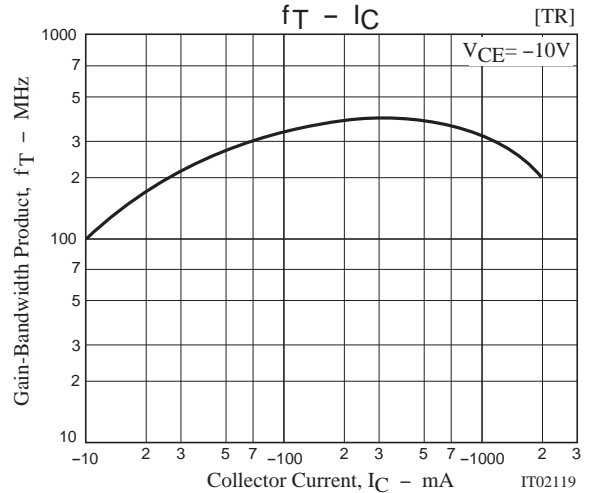
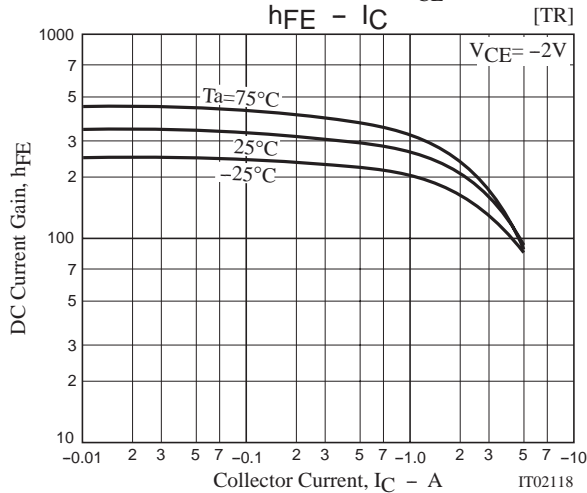
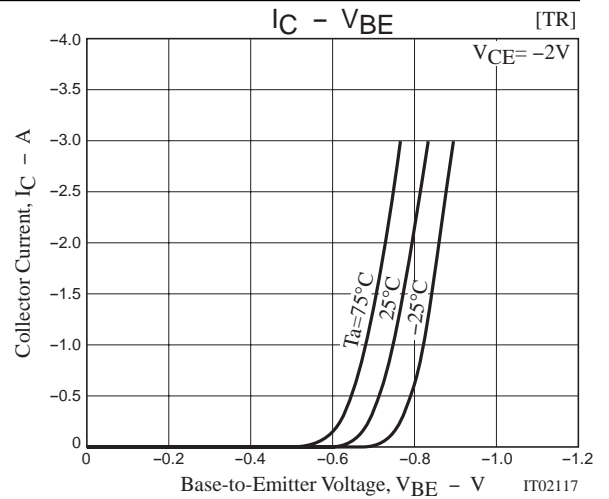
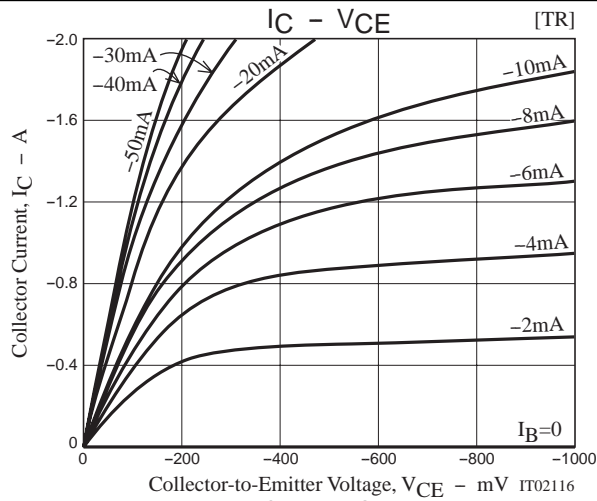


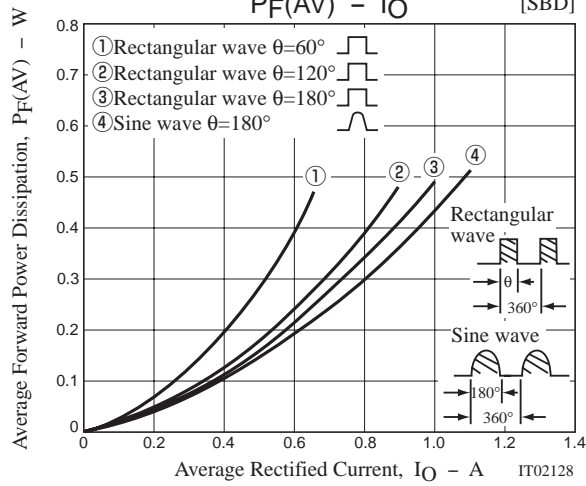
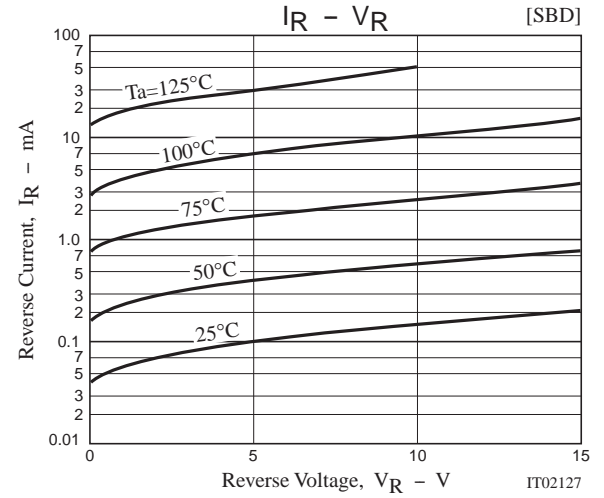
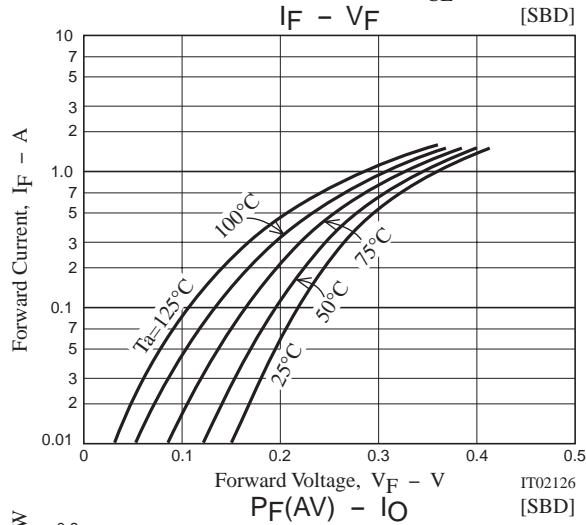
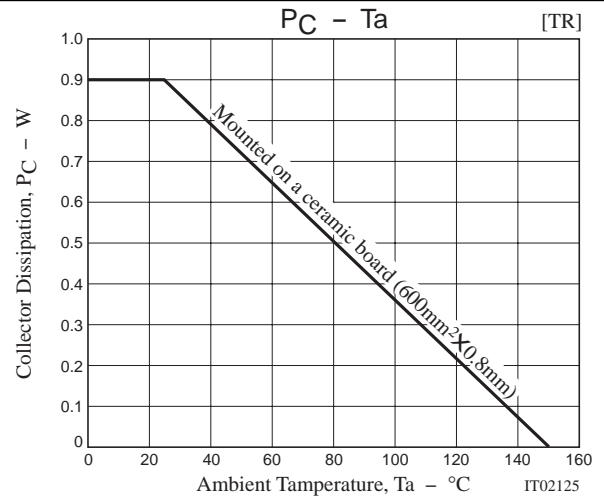
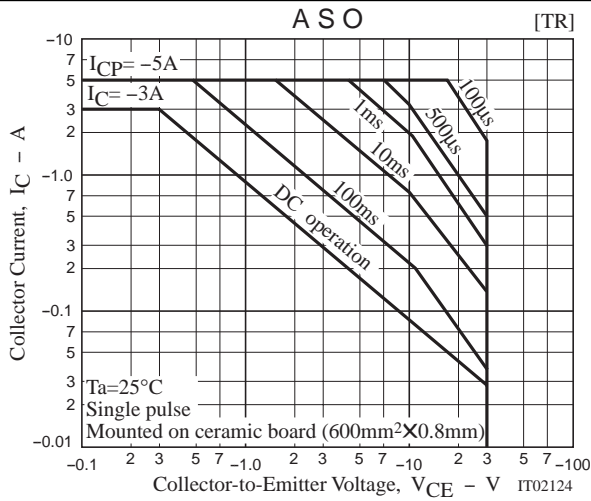
Switching Time Test Circuit



t_{rr} Test Circuit







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